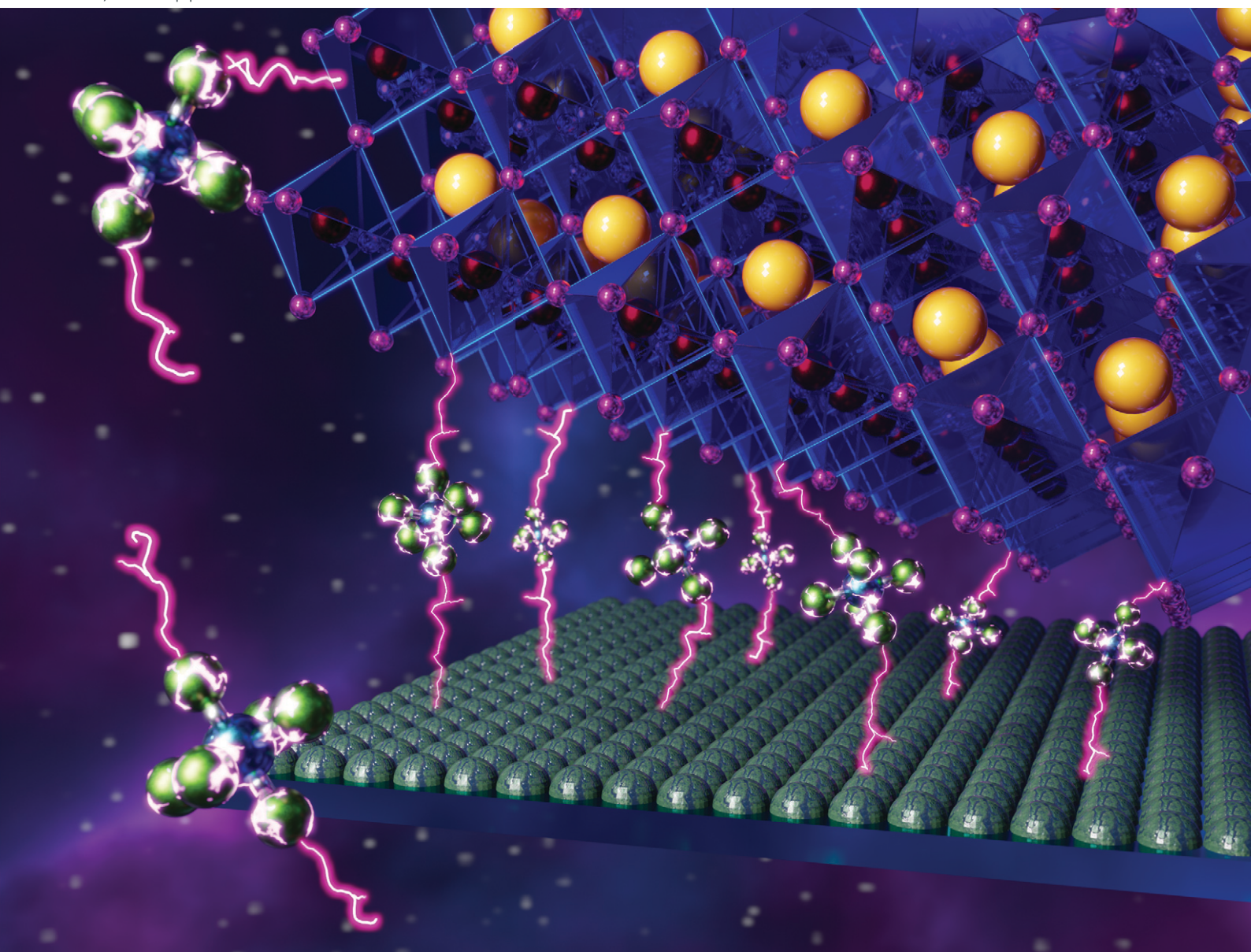


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## PAPER

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# Interfacial modification between NiO<sub>x</sub> and perovskite layers with hexafluorophosphate salts for enhancing device efficiency and stability of perovskite solar cells†

Zong-Xuan She and Sheng-Hsiung Yang \*

Inorganic metal oxides like nickel oxides (NiO<sub>x</sub>) have been largely adopted as hole transport layers (HTLs) for the fabrication of perovskite solar cells (PSCs). Reducing interfacial defects between the NiO<sub>x</sub> HTL and the perovskite absorbing layer is always a key issue in achieving high efficiency and long-term stability of PSCs. In this work, we first utilized inorganic hexafluorophosphate salts including NH<sub>4</sub>PF<sub>6</sub>, LiPF<sub>6</sub>, and NaPF<sub>6</sub> to modify the surface of NiO<sub>x</sub> through interactions between Ni atoms and PF<sub>6</sub><sup>−</sup> groups. The incorporation of those salts not only decreased the defects at the NiO<sub>x</sub>/perovskite interface but also optimized the energy levels of NiO<sub>x</sub> to match with the perovskite. After the surface passivation of NiO<sub>x</sub>, the up-lying perovskite consequently exhibited larger grain sizes and shorter carrier lifetime. The PSC based on an NH<sub>4</sub>-PF<sub>6</sub>-modified NiO<sub>x</sub> HTL showed the best efficiency of 17.28% and a long device lifetime of over 108 days, which was significantly better than the controlled device using the pristine NiO<sub>x</sub> layer. Our experimental results demonstrate that interface modification of NiO<sub>x</sub> by hexafluorophosphate salts is an effective strategy to optimize the performance of PSCs.

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## 1. Introduction

Perovskites have garnered substantial research interest for photovoltaic applications owing to their high visible light absorption, long carrier diffusion length, high carrier mobility, low exciton binding energy, and tunable bandgap.<sup>1–4</sup> In recent years, the development of perovskite solar cells (PSCs) in laboratories has been rapidly boosted with the best efficiency of 26.1%.<sup>5</sup> The chemical formula of perovskite materials is ABX<sub>3</sub>, where A can be an organic/inorganic monovalent cation, B is a divalent metal cation, and X is a halide anion. Monocationic perovskites have been extensively utilized as active layers in PSCs, like methylammonium lead iodide (MAPbI<sub>3</sub>), formamidinium lead iodide (FAPbI<sub>3</sub>), and cesium lead iodide (CsPbI<sub>3</sub>).<sup>6–8</sup> However, monocationic perovskites are considered to exhibit low thermal and moisture stability, which hinders their applicability to PSCs. To improve the stability and efficiency of PSCs, the mainstream approach adopts mixed cation perovskites as active layers.<sup>9</sup> Li *et al.* utilized a

mixed cation perovskite FA<sub>1−x</sub>MA<sub>x</sub>PbI<sub>3</sub> with a FA<sup>+</sup>:MA<sup>+</sup> molar ratio of 0.7:0.3 as a light absorber.<sup>10</sup> The best device achieved a maximum power conversion efficiency (PCE) of 16%, an open-circuit voltage (*V*<sub>OC</sub>) of 1.03 V, a short-circuit current density (*J*<sub>SC</sub>) of 22.6 mA cm<sup>−2</sup>, and a fill factor (FF) of 0.68. Furthermore, the unsealed device retained its performance without any PCE loss for 20 days in an ambient environment. Bolink and his coworkers demonstrated a triple-cation Cs<sub>0.5</sub>FA<sub>0.4</sub>MA<sub>0.1</sub>Pb(I<sub>0.83</sub>Br<sub>0.17</sub>)<sub>3</sub> perovskite film by simultaneous thermal vacuum deposition.<sup>11</sup> The optical absorption of the triple-cation perovskite layer was unaltered for days during continuous exposure to air at 25 °C and 40% relative humidity (RH) condition. The optimized PSC showed the best PCE of 16% with negligible hysteresis and an external quantum efficiency (EQE) of 70–85% in the whole visible light range. It is undeniable that using multi-cation perovskite materials is one of the key factors to enhance the efficiency and stability of PSCs.

PSCs with a p–i–n configuration offer various advantages including straightforward fabrication, optimal energy level alignment, little hysteresis effect, and long-term stability.<sup>12–16</sup> Choosing suitable hole transport materials is critical for enabling efficient hole extraction and suppressing detrimental electron recombination. Common hole transport layers (HTLs) for PSCs include inorganic metal oxides (such

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as  $\text{NiO}_x$  and  $\text{CuO}_x$ ) and conductive polymers (like P3HT, PTAA, and PEDOT:PSS).<sup>17,18</sup> The high price, low hole mobility, and unsuitable energy level alignments of organic polymers limit the development of PSCs using organic HTLs.<sup>19–21</sup> In comparison, inorganic oxides have several benefits for fabricating efficient and stable PSCs, including optimal band alignment with perovskites, low resistivity, environmental stability, and cost-effectiveness.<sup>22</sup> Among inorganic HTLs,  $\text{NiO}_x$  is extensively utilized because of easy processing, low cost, high transmittance in the visible range, and facile preparation of precursor solutions. However, direct contact between  $\text{NiO}_x$  and perovskites usually generates issues that reduce the efficiency and stability of PSCs. In accordance with prior research reports,<sup>23,24</sup>  $\text{Ni}^{3+}$  on the  $\text{NiO}_x$  surface is predisposed to interfacial redox reactions with A-site cations of the perovskite, consuming the ratio of  $\text{Ni}^{3+}$  in  $\text{NiO}_x$ , thereby decreasing intrinsic conductivity and increasing charge recombination. In addition, this accelerates the deprotonation of the organic ammonium group to amine precursor and perovskite degradation to induce severe instability of devices.

To manufacture highly efficient and stable PSCs, addressing surface defects in  $\text{NiO}_x$  is crucial. Here, we demonstrate that inorganic hexafluorophosphate salts, like  $\text{NH}_4\text{PF}_6$ ,  $\text{LiPF}_6$  and  $\text{NaPF}_6$ , can effectively passivate surface defects of  $\text{NiO}_x$  and significantly improve device performance. The device architecture of our PSCs is depicted in Fig. 1. In this work, the  $\text{NiO}_x$ /perovskite interfacial contact was modified by introducing an ultrathin layer of  $\text{NH}_4\text{PF}_6$ ,  $\text{LiPF}_6$ , or  $\text{NaPF}_6$  to prevent direct contact between  $\text{NiO}_x$  and perovskites, as shown in Fig. 1. The  $\text{PF}_6^-$  groups can interact with Ni atoms to tightly attach to the  $\text{NiO}_x$  layer. The salt modification can effectively enhance the carrier extraction capability of  $\text{NiO}_x$  owing to reduced defects and favorable energy level alignment. The experimental results reveal that the  $\text{NH}_4\text{PF}_6$ ,  $\text{LiPF}_6$ , and  $\text{NaPF}_6$ -modified  $\text{NiO}_x$  devices exhibited the best PCE of 17.28%, 14.87%, and 14.88%, respectively, relative to the controlled device with a PCE of 13.98%. Moreover, the modified devices showed preferable steady-state PCE output and much longer device lifetime up to 108 days.

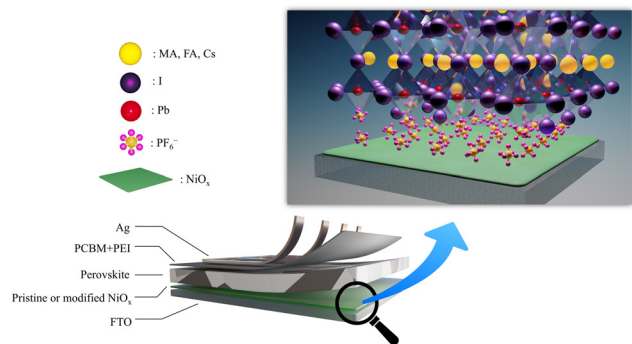


Fig. 1 Device architecture of PSCs with the enlarged illustration of the salt-modified  $\text{NiO}_x$ /perovskite interface.

## 2. Experimental section

### 2.1 Materials

The patterned fluorine-doped tin oxide (FTO,  $7 \Omega$  per square)-coated glass substrates were bought from LiveStrong Optoelectronics Technology Co., Ltd. Nickel acetate tetrahydrate ( $\text{Ni}(\text{OAc})_2 \cdot 4\text{H}_2\text{O}$ , purity 98+%), lead bromide ( $\text{PbBr}_2$ , purity 98+%), lead iodide ( $\text{PbI}_2$ , purity 99.9985%), and cesium iodide ( $\text{CsI}$ , purity 99.9%) were purchased from Alfa Aesar. Methylammonium bromide (MABr, purity 98.0%) and formamidinium iodide (FAI, purity 98%) were bought from TCI and Greatcell Solar Materials Pty Ltd., respectively. Ethanolamine (purity 99%) and tetra-*n*-butylammonium tetrafluoroborate (TBABF<sub>4</sub>, purity 98%) were purchased from Acros. [6,6]-Phenyl- $\text{C}_{61}$ -butyric acid methyl ester (PC<sub>61</sub>BM, purity 99%) was bought from Solenne B. V. Polyethyleneimine (PEI, molecular weight 25 000  $\text{g mol}^{-1}$ ) was bought from Sigma-Aldrich. Three hexafluorophosphate salts, including lithium hexafluorophosphate ( $\text{LiPF}_6$ , purity 98%), sodium hexafluorophosphate ( $\text{NaPF}_6$ , purity 98%), and ammonium hexafluorophosphate ( $\text{NH}_4\text{PF}_6$ , purity 99%), were purchased from Thermo Fisher Scientific, Matrix Scientific, and Sigma-Aldrich, respectively. Other solvents were purchased from Alfa Aesar or Acros and used without further purification.

### 2.2 Preparation of $\text{NiO}_x$ layers

$\text{Ni}(\text{OAc})_2 \cdot 4\text{H}_2\text{O}$  (0.124 g, 0.5 mmol) and 30  $\mu\text{L}$  of ethanolamine were dissolved in 5 mL of isopropanol (IPA). The solution was heated and stirred at 70  $^\circ\text{C}$  for 24 h to form a translucent green precursor solution. The precursor solution was then spin-coated onto the FTO substrate at a speed of 1500 rpm for 30 s. The substrate was dried at 75  $^\circ\text{C}$  for 10 min and then calcined in a high-temperature oven at 450  $^\circ\text{C}$  for 1 h to obtain the pristine  $\text{NiO}_x$  layer. To prepare the modified  $\text{NiO}_x$  films,  $\text{NH}_4\text{PF}_6$  (0.6  $\text{mg mL}^{-1}$  in acetonitrile),  $\text{NaPF}_6$  (0.6  $\text{mg mL}^{-1}$  in methanol), or  $\text{LiPF}_6$  (0.6  $\text{mg mL}^{-1}$  in methanol) was individually spin-coated on different  $\text{NiO}_x$  from their solutions at 1000 rpm for 30 s and dried at 80  $^\circ\text{C}$  for 10 min.

### 2.3 Device fabrication

The device structure in this study is FTO/pristine or modified  $\text{NiO}_x$ /perovskite/PCBM + TBABF<sub>4</sub>/PEI/Ag. The FTO substrates were sequentially sonicated in detergent, deionized water, acetone, and IPA for 20 min, followed by oxygen plasma treatment for 15 min. The pristine or modified  $\text{NiO}_x$  layers as the HTLs were prepared on the FTO substrates according to section 2.2. The perovskite layer was then deposited on top of the  $\text{NiO}_x$  HTL, followed by the deposition of the PCBM + TBABF<sub>4</sub> layer as the electron transport layer (ETL). The details for the preparation and deposition of the perovskite and PCBM + TBABF<sub>4</sub> layers were referred to our previous report.<sup>25</sup> Afterward, 0.1 mol% PEI in anhydrous IPA was spin-coated onto the PCBM layer at 4500 rpm for 30 s. Finally, 100 nm-thick Ag electrodes were thermally evaporated under a base



pressure of  $8 \times 10^{-6}$  torr. The active area of each device is  $4.5 \text{ mm}^2$ .

## 2.4 Characterization

The current density–voltage ( $J$ – $V$ ) characteristics of PSCs were recorded using a Keithley 2400 source meter under simulated AM 1.5G solar irradiation (1000 W xenon short arc lamp,

Yamashita Denso YSS-100A). The dark current measurement of PSCs was performed using the same source meter in the dark environment. EQE and integrated current density data were measured using a self-assembled system consisting of a Keithley 2400 source meter, an ABET Technologies LS 150 xenon lamp, and a Prince Instruments Acton 2150 monochromator. To investigate the stability of the devices, the encapsulated PSCs were stored in a humidity control box

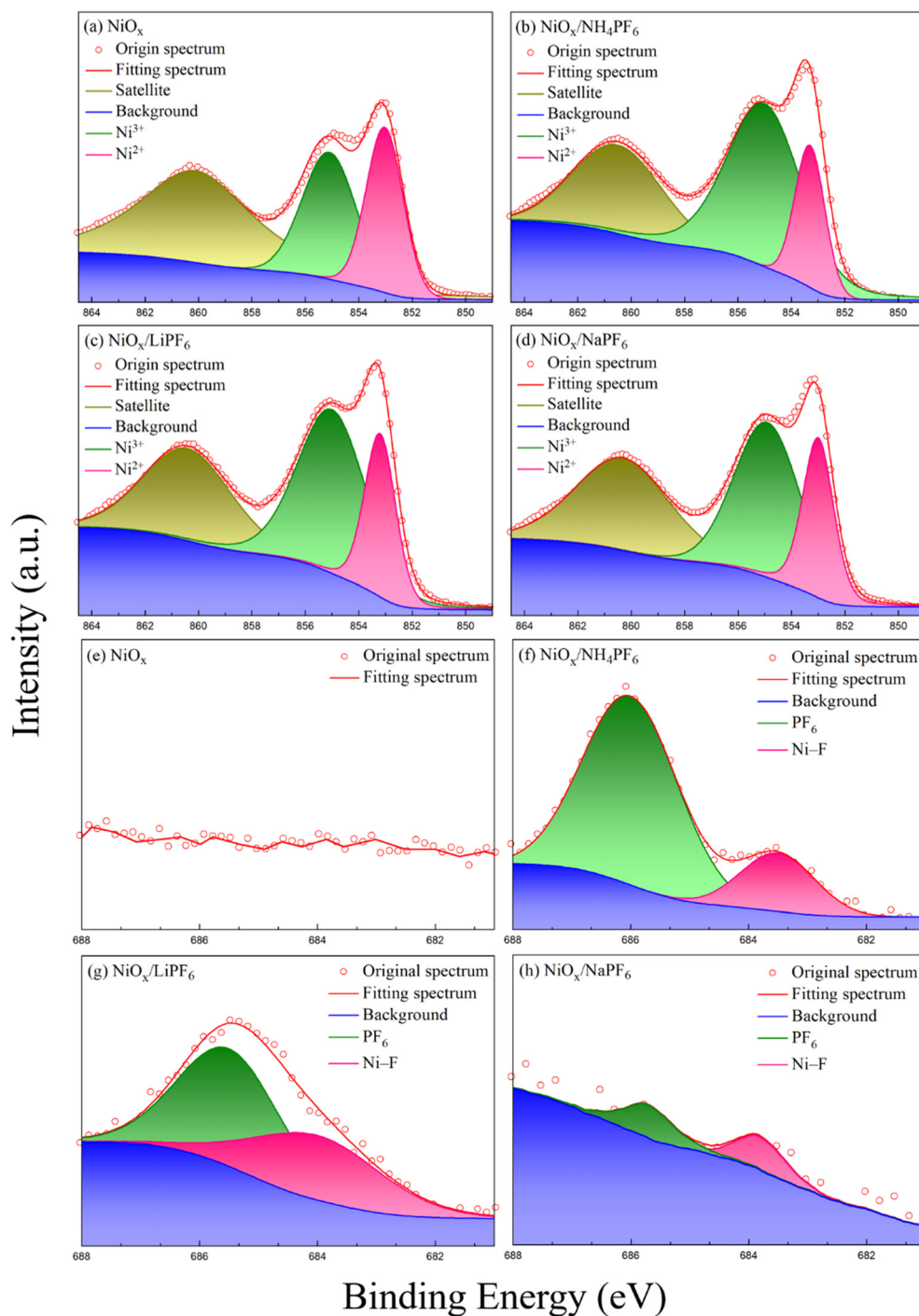


Fig. 2 XPS spectra of (a–d) Ni 2p and (e–h) F 1s elements in the pristine and modified NiO<sub>x</sub> films.



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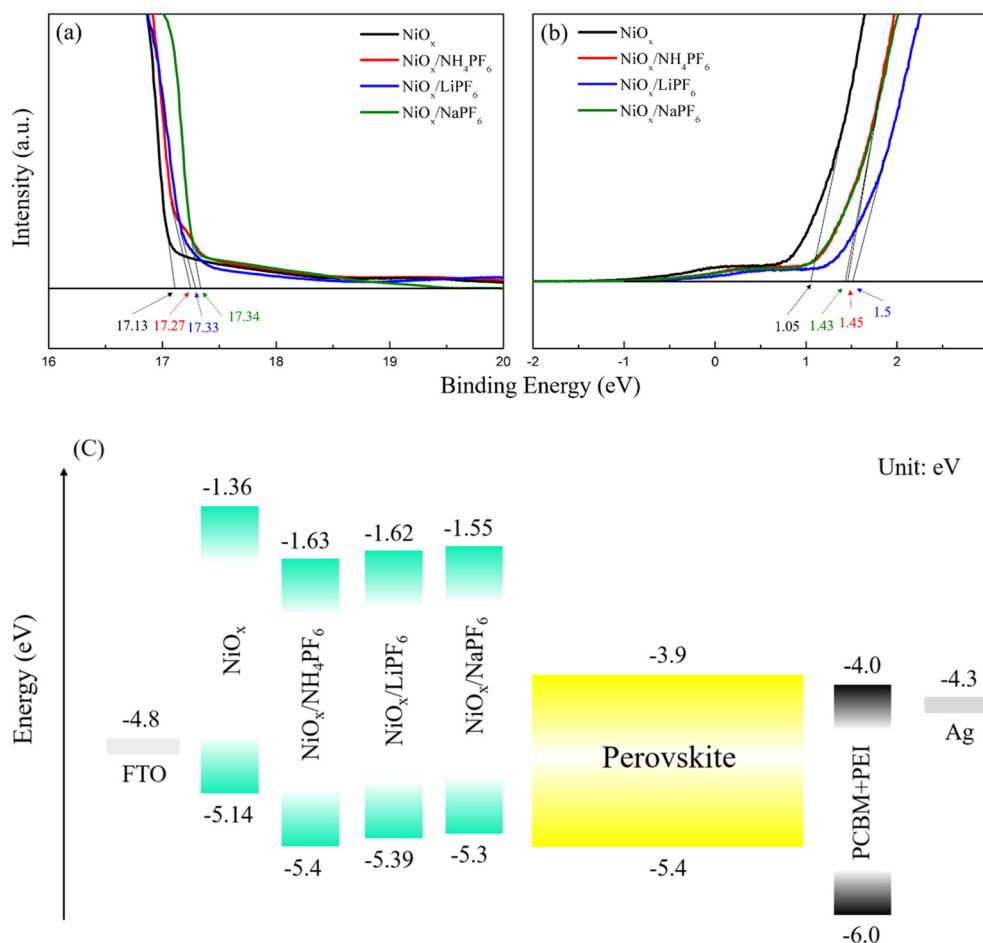


Fig. 3 UPS spectra of the pristine and modified NiO<sub>x</sub> films in the (a) low and (b) high binding energy regions; (c) energy level diagram of PSCs.

blocking behaviors. As mentioned in the XPS analysis, the incorporation of hexafluorophosphate salts makes NiO<sub>x</sub> exhibit more p-type properties with higher hole concentration, and therefore the VB level of the modified NiO<sub>x</sub> shows a downward shift. Among the three salt-modified NiO<sub>x</sub>, we speculate that the difference in energy levels originates from different types and ionic sizes of the three cations (NH<sub>4</sub><sup>+</sup>, Li<sup>+</sup>, and Na<sup>+</sup>). In particular, NH<sub>4</sub><sup>+</sup> has the largest ionic size that is suitable for occupying Ni<sup>2+</sup> sites and modifying energy levels of NiO<sub>x</sub>.

### 3.2 Characterization of perovskites on different NiO<sub>x</sub> films

It is understandable that a smooth defect-free NiO<sub>x</sub> surface is favorable for the formation of high-quality perovskite layers with larger grain sizes and fewer boundaries. The SEM images of the perovskite films deposited on the pristine and modified NiO<sub>x</sub> are displayed in Fig. 4, revealing discernible differences in perovskite morphology and grain size. Compared to perovskites on the pristine NiO<sub>x</sub>, the perovskite films deposited on the salt-modified NiO<sub>x</sub> exhibit markedly larger grain sizes, indicating that the interface modification facilitates favorable perovskite crystallization and grain growth. As for the SEM images in Fig. 4b–d, the

morphological difference of the perovskite comes from NiO<sub>x</sub> underlayers with different surface properties which were modified by various salts carrying different cations. Among them, NH<sub>4</sub>PF<sub>6</sub>-modified NiO<sub>x</sub> has the lowest roughness, causing the largest perovskite grain size (average 566.7 nm). The large grain size of perovskites with fewer boundaries can effectively reduce charge recombination, thereby enhancing the extraction and transport of carriers. In addition to SEM observation, XRD analysis was also performed to provide the crystallinity of perovskite films deposited on the different NiO<sub>x</sub> layers. In Fig. S4,† several intense diffraction peaks at  $2\theta = 14.2^\circ, 19.9^\circ, 24.5^\circ, 28.3^\circ, 31.8^\circ, 35^\circ, 40.5^\circ$ , and  $43.1^\circ$  were observed, corresponding to the (001), (011), (111), (002), (012), (112), (022), and (003) planes of the cubic perovskite phase, respectively, which are consistent with the previous reports.<sup>32</sup> Additionally, the perovskite films deposited on the salt-modified NiO<sub>x</sub> exhibit more intense diffraction peaks, indicating that salt incorporation promotes the growth of perovskite grains with higher crystallinity.

The PL spectra in Fig. 5a demonstrate that the perovskites grown on the salt-modified NiO<sub>x</sub> films exhibit lower PL intensity compared to that on the pristine NiO<sub>x</sub>. The results suggest that interface modification enhances the carrier extraction of the NiO<sub>x</sub> HTL and suppresses charge



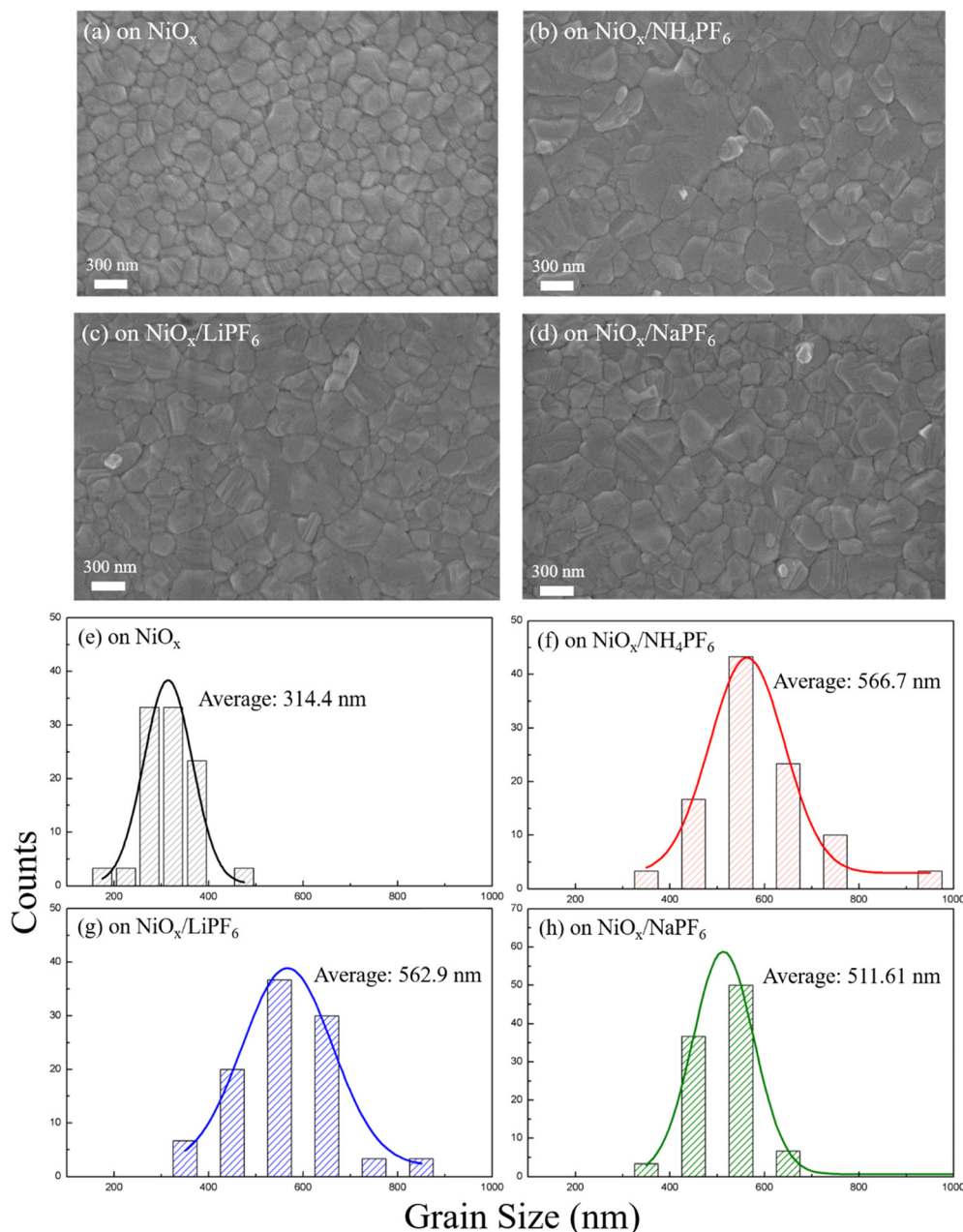


Fig. 4 (a–d) Top-view SEM images and (e–h) grain size distribution of perovskite films on the pristine or modified  $\text{NiO}_x$  layers.

recombination. Among the three salts,  $\text{NH}_4\text{PF}_6$  modification induces the most pronounced decrease in PL intensity, indicating its effective passivation capability to bring improvements in  $J_{\text{SC}}$  and FF of PSCs. To further corroborate the phenomenon of PL attenuation, TR-PL decay measurements of the perovskite films deposited on the various  $\text{NiO}_x$  layers were carried out and the corresponding decay curves are displayed in Fig. 5b. The fast-decay constant  $\tau_1$ , slow-decay constant  $\tau_2$ , and average carrier lifetime  $\tau_{\text{avg}}$  from the bi-exponential fitting of PL decay curves are listed in Table S1.† The perovskites on the pristine  $\text{NiO}_x$  and  $\text{NH}_4\text{PF}_6$ ,  $\text{LiPF}_6$ , and  $\text{NaPF}_6$ -modified  $\text{NiO}_x$  have a  $\tau_{\text{avg}}$  of 230.8, 88.3, 144, and 185.1 ns, respectively. The reduced  $\tau_{\text{avg}}$  can be

attributed to the enhanced carrier extraction ability of  $\text{NiO}_x$  to reduce the PL emission of the perovskites. Apparently, the TR-PL decay results are in agreement with the downtrend of PL intensity. The change in TR-PL decay curves and carrier lifetime can be realized by interface modification of  $\text{NiO}_x$  using the three hexafluorophosphate salts with different cations, as discussed in the previous UPS analysis and SEM observation of perovskites. We notice that  $\text{NH}_4\text{PF}_6$  incorporation leads to the shortest carrier lifetime of perovskites and therefore, the best PSC performance based on the  $\text{NH}_4\text{PF}_6$ -modified  $\text{NiO}_x$  HTL is expected. To summarize, the passivation of surface defects by salt insertion between  $\text{NiO}_x$  and perovskite layers brought about



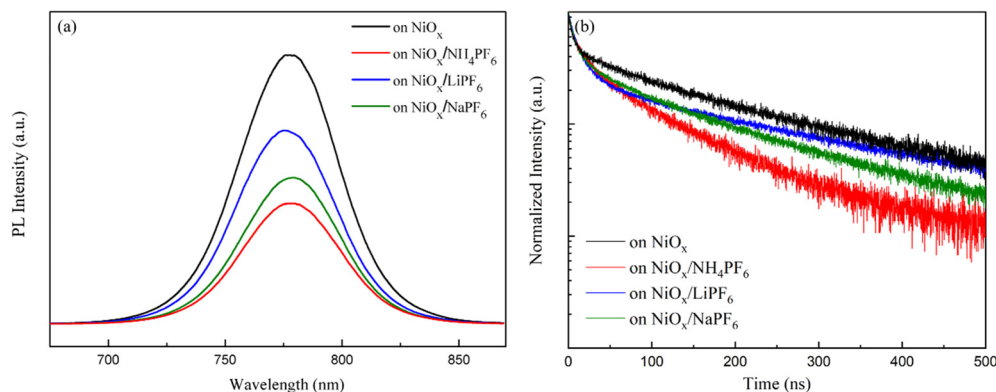


Fig. 5 (a) PL emission spectra and (b) TR-PL decay curves of the perovskites on the pristine NiO<sub>x</sub> and NH<sub>4</sub>PF<sub>6</sub>, LiPF<sub>6</sub>, and NaPF<sub>6</sub>-modified NiO<sub>x</sub> films.

improved conductivity, lowered surface roughness, and enhanced carrier extraction ability of NiO<sub>x</sub>. Meanwhile, larger perovskite grains as well as matched energy levels at the NiO<sub>x</sub>/perovskite interface were acquired.

### 3.3 Electrical and stability measurements of PSCs

The device architecture in this study is FTO/pristine or modified NiO<sub>x</sub>/perovskite/PCBM + TBABF<sub>4</sub>/PEI/Ag, where NH<sub>4</sub>PF<sub>6</sub>, LiPF<sub>6</sub>, or NaPF<sub>6</sub> is solely inserted between NiO<sub>x</sub> and the perovskite layer as the modifier. It is important to reduce the redox reaction at the NiO<sub>x</sub>/perovskite interface to improve the device efficiency and stability. Two small molecules, 4-(2-aminoethyl)benzoic acid bromide and potassium thiocyanate, were proposed to be inserted between the NiO<sub>x</sub> HTL and

perovskite film to diminish the redox reaction between the two layers in the literature.<sup>37,38</sup> In this study, hexafluorophosphate salts were selected to deposit on top of NiO<sub>x</sub> to prevent direct contact between NiO<sub>x</sub> and the perovskite surface, thus delaying the degradation of perovskite films. To evaluate the influences of interfacial defects and density of trap states on charge transport within devices, dark currents of PSCs with the pristine and modified NiO<sub>x</sub> HTLs were measured, as shown in Fig. S5.† Under the reverse bias from −1 to 0 V, PSCs with NH<sub>4</sub>PF<sub>6</sub> and LiPF<sub>6</sub>-modified NiO<sub>x</sub> HTLs exhibited lower leakage current density compared with the pristine NiO<sub>x</sub> device, meaning that charge extraction was facilitated and recombination was mitigated through interface modification. Specifically, NH<sub>4</sub>PF<sub>6</sub> possesses the most significant passivation ability among the

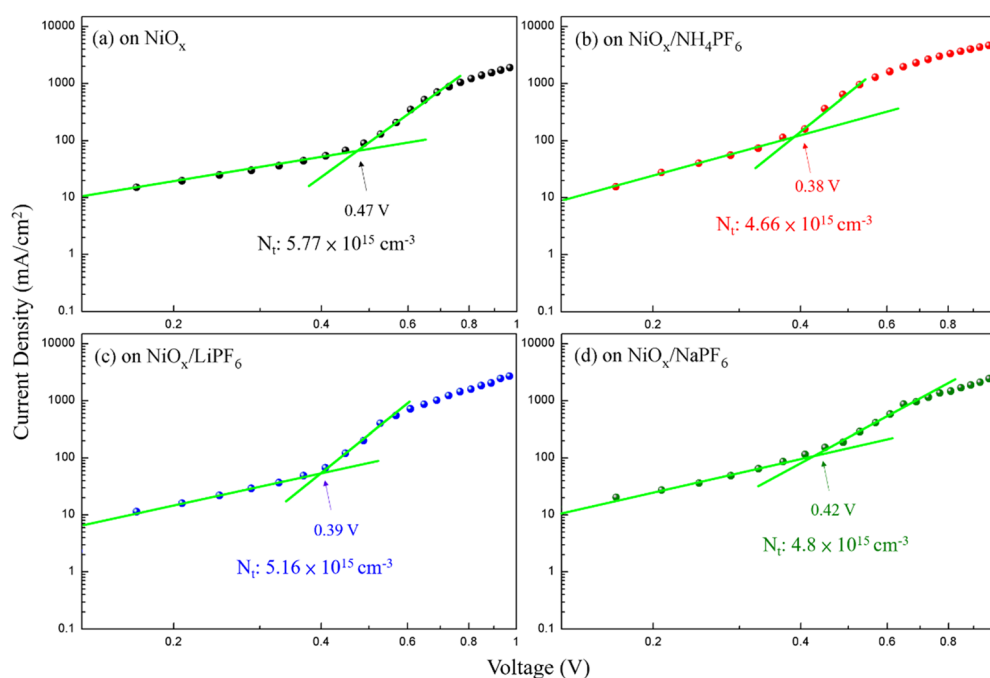


Fig. 6 Dark *J*-*V* characteristics of PSCs based on the (a) pristine NiO<sub>x</sub> and (b) NH<sub>4</sub>PF<sub>6</sub>-, (c) LiPF<sub>6</sub>-, and (d) NaPF<sub>6</sub>-modified NiO<sub>x</sub> with the SCLC analysis.





three salts to promote the device performance. The defect densities ( $N_t$ ) were calculated *via* the space-charge-limited current (SCLC) analysis,<sup>39,40</sup> as depicted in Fig. 6. The  $N_t$  values of the devices were computed by eqn (1):

$$N_t = \frac{2\epsilon_0\epsilon_r V_{TFL}}{qL^2} \quad (1)$$

where  $V_{TFL}$ ,  $\epsilon_0$ ,  $\epsilon_r$ ,  $q$ , and  $L$  represent the trap-filled limit voltage, vacuum permittivity, relative dielectric constant of the perovskite  $\text{Cs}_{0.05}\text{FA}_{0.81}\text{MA}_{0.14}\text{Pb}(\text{Br}_{0.15}\text{I}_{0.85})_3$ ,<sup>41</sup> elementary charge, and the thickness of the perovskite film. Through the salt modification of the  $\text{NiO}_x$  films, the  $V_{TFL}$  was determined to be 0.47, 0.38, 0.39, and 0.42 V for the pristine  $\text{NiO}_x$  and  $\text{NH}_4\text{PF}_6$ ,  $\text{LiPF}_6$ , and  $\text{NaPF}_6$ -modified  $\text{NiO}_x$  PSCs, respectively. Moreover, the  $N_t$  value was reduced from  $5.77 \times 10^{15} \text{ cm}^{-3}$  for the pristine  $\text{NiO}_x$  device to  $4.66 \times 10^{15}$ ,  $5.16 \times 10^{15}$ , and  $4.8 \times 10^{15} \text{ cm}^{-3}$  for the  $\text{NH}_4\text{PF}_6$ ,  $\text{LiPF}_6$ , and  $\text{NaPF}_6$ -modified  $\text{NiO}_x$  PSCs, respectively. The results demonstrate that salt modification effectively passivated the interfacial defects between  $\text{NiO}_x$  and the perovskite. The photovoltaic performance of the devices was assessed under AM 1.5G illumination at  $100 \text{ mW cm}^{-2}$  and the  $J$ - $V$  characteristics of the PSCs are displayed in Fig. 7a. The controlled device based on the pristine  $\text{NiO}_x$  HTL had the best PCE of 13.98% and average  $J_{SC}$  of  $20.46 \text{ mA cm}^{-2}$ ,  $V_{OC}$  of 0.97 V, FF of 65.39%, and PCE of 12.94% from 30 devices. The champion PSC was achieved by incorporating the  $\text{NH}_4\text{PF}_6$ -modified  $\text{NiO}_x$  film with a maximum PCE of 17.28% and average  $J_{SC}$  of  $21.86 \text{ mA cm}^{-2}$ ,  $V_{OC}$  of 1.01 V, FF of 70.97%, and PCE of 15.62%. The enhanced performance can be attributed to the passivation of interfacial defects, high-quality perovskite crystals, and favorable energy level alignment between  $\text{NiO}_x$  and the perovskite by introducing  $\text{NH}_4\text{PF}_6$  as the surface modifier. Besides, the device using the  $\text{LiPF}_6$ -modified  $\text{NiO}_x$  film as the HTL exhibited a maximum PCE of 14.87% and average  $J_{SC}$  of  $20.99 \text{ mA cm}^{-2}$ ,  $V_{OC}$  of 0.97 V, FF of 68.54%, and PCE of 14.03%. By using the  $\text{NaPF}_6$ -modified  $\text{NiO}_x$  HTL, the device exhibited a maximum PCE of 14.88% and average  $J_{SC}$  of  $20.73 \text{ mA cm}^{-2}$ ,  $V_{OC}$  of 0.99 V, FF of 69.3%, and PCE of 14.26%, which was still better than the controlled device. Table 1 presents the best PCE and average photovoltaic

parameters from 30 devices incorporating the pristine or salt-modified  $\text{NiO}_x$  HTL. The performance of our devices is not very good as compared to those of reported  $\text{NiO}_x$ -based perovskite solar cells with a PCE of 18.75–20.13% or a long device lifetime over 3000 h,<sup>42,43</sup> mainly due to different processing equipment and environments. Limited by our processing facilities, the devices were not manufactured under low water/oxygen conditions throughout the entire process. Besides, the electrical measurements of our devices were carried out in an ambient environment. The above factors may affect the performance of PSCs. Fig. 7b displays the integrated current density curves and EQE spectra of PSCs using the pristine and salt-modified  $\text{NiO}_x$  HTLs from 300 to 830 nm. The results demonstrate the substantially enhanced EQE values for the devices incorporating salt-modified  $\text{NiO}_x$  compared to the pristine one, with  $\text{NH}_4\text{PF}_6$  modification exhibiting the most pronounced improvement. The integrated current density was acquired to be 19.12, 20.7, 20.3, and 19.6  $\text{mA cm}^{-2}$  for the pristine  $\text{NiO}_x$  and  $\text{NH}_4\text{PF}_6$ ,  $\text{LiPF}_6$ , and  $\text{NaPF}_6$ -modified  $\text{NiO}_x$  devices, respectively, which coordinated well with the measured  $J_{SC}$  values.

Light intensity dependent  $J_{SC}$  and  $V_{OC}$  measurements were conducted to elucidate the interfacial carrier recombination process. The correlation between  $J_{SC}$  and illumination intensity is shown in Fig. 8a, which follows a power law relation:  $J_{SC} \propto I^\alpha$ , where  $I$  is the light intensity and  $\alpha$  is the exponential factor.<sup>44</sup> The  $\alpha$  of the PSCs with salt-modified  $\text{NiO}_x$  HTLs ( $\sim 0.995$ ) is closer to 1 that is higher than the controlled device ( $\alpha = 0.94$ ), meaning that the  $J_{SC}$  of the salt-modified devices is approximately proportional to the incident light intensity and the recombination is inhibited.<sup>45</sup> Fig. 8b depicts the relationship between  $V_{OC}$  and light intensity, revealing that the slope of the three salt-modified  $\text{NiO}_x$  devices is higher than that of the controlled one. According to the previous literature,<sup>46,47</sup> the relationship between  $V_{OC}$  and light intensity can be described by eqn (2):

$$V_{oc} = \left( \frac{nKT}{q} \right) \ln \left( \frac{J_{sc}}{J_0} + 1 \right) \quad (2)$$

where  $n$  is the ideality factor,  $K$  is Boltzmann's constant,  $T$  is the absolute temperature,  $q$  is the elementary charge,  $J_{SC}$  is

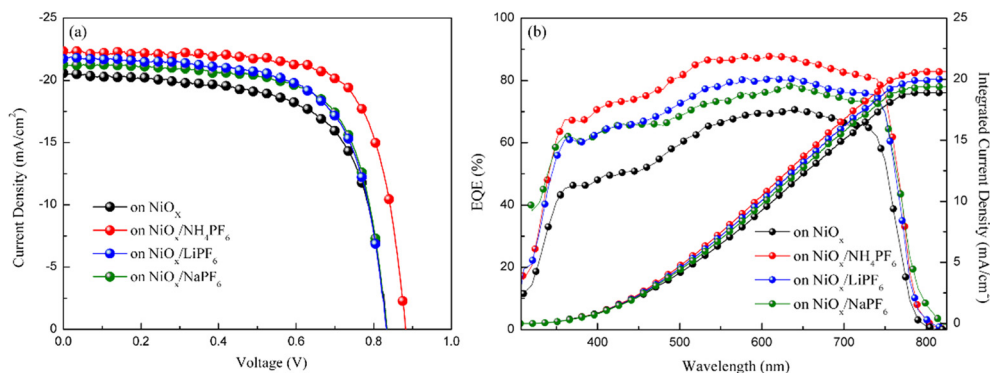


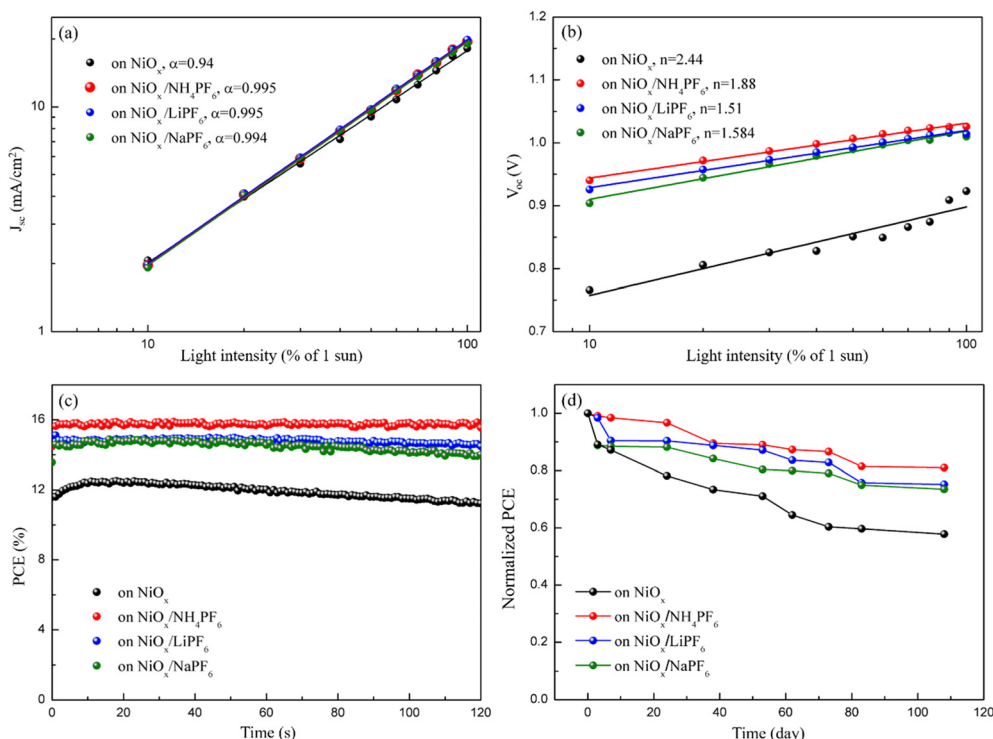
Fig. 7 (a)  $J$ - $V$  characteristics and (b) EQE spectra and integrated current density of PSCs based on the pristine and modified  $\text{NiO}_x$  HTLs.



**Table 1** Photovoltaic parameters of PSCs based on the pristine and modified NiO<sub>x</sub> HTLs

Devices	Best PCE (%)	$J_{SC}^a$ (mA cm <sup>-2</sup> )	$V_{OC}^a$ (V)	FF <sup>a</sup> (%)	PCE <sup>a</sup> (%)
Pristine	13.98	20.46	0.97	65.39	12.94
NiO <sub>x</sub> /NH <sub>4</sub> PF <sub>6</sub>	17.28	21.82	1.01	70.97	15.62
NiO <sub>x</sub> /LiPF <sub>6</sub>	14.87	20.99	0.97	68.54	14.03
NiO <sub>x</sub> /NaPF <sub>6</sub>	14.88	20.73	0.99	69.3	14.26

<sup>a</sup> The average photovoltaic parameters were obtained from 30 devices.



**Fig. 8** (a)  $J_{SC}$  and (b)  $V_{OC}$  values versus light intensity, (c) steady-state PCE output at the maximum power point, and (d) stability test of PSCs based on the pristine and modified NiO<sub>x</sub> HTLs.

the photo-generated current density, and  $J_0$  is the dark saturation current. As evident in the  $V_{OC}$ -light intensity relation, the ideality factor  $n$  typically denotes the dominant recombination mechanism in solar cells.<sup>48</sup> The reduction in the  $n$  value indicates that the trap-mediated Shockley-Read-Hall (SRH) recombination through interfacial defects is prohibited.<sup>49</sup> The  $n$  values of the devices with the NH<sub>4</sub>PF<sub>6</sub>, LiPF<sub>6</sub>, and NaPF<sub>6</sub>-modified HTLs ( $n = 1.88$ ,  $1.51$ , and  $1.584$ ) are smaller than that of the controlled device ( $n = 2.44$ ), showing effective suppression of the SRH recombination pathway by salt incorporation. Fig. 8c plots the steady-state PCE output at the maximum power point of the corresponding devices before and after salt modification. The PCE of the unmodified device gradually decreased from 12.74% to 11.46% within 120 s, while the three salt-modified devices possessed a stable PCE output, indicative of excellent photostability. To explore the device lifetime of the PSCs, the manufactured PSCs were stored in a humidity control box at room temperature with 40% RH and their device

performance was acquired at certain intervals, as shown in Fig. 8d. After 108 days, the PCE of the unmodified device decreased by 42.17% of the initial efficiency; moreover, the PCE of devices modified with NH<sub>4</sub>PF<sub>6</sub>, LiPF<sub>6</sub>, and NaPF<sub>6</sub> salts was reduced by only 19%, 24%, and 26.5% of the original efficiency, respectively. The improvement in the stability of the PSCs by salt modification can be attributed to the reduction in defect state density and optimized contact at the NiO<sub>x</sub>/perovskite interface, as mentioned in the previous section.

## 4. Conclusions

The three hexafluorophosphate salts were proven to serve as effective interfacial modifiers for NiO<sub>x</sub> in reducing defects and enhancing the photovoltaic performance of PSCs. Relative to the unmodified device, the devices based on the salt-modified NiO<sub>x</sub> showed markedly enhanced performance. Notably, the utilization of NH<sub>4</sub>PF<sub>6</sub>-modified



NiO<sub>x</sub> yielded optimal results, with a maximum PCE of 17.28% and excellent device lifetime of up to 108 days. The performance enhancement is attributed to advantageous energy level alignment, passivation of interfacial carrier traps, and perovskite grain quality. This work demonstrates not only a simple strategy toward defect passivation in PSCs but also the functionality of the interlayer between NiO<sub>x</sub> and the perovskite to improve the device efficiency and stability.

## Conflicts of interest

There are no conflicts to declare.

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